

Electronic Supplementary Information

Facile Approach to Surface Functionalized MoS₂ Nanosheets

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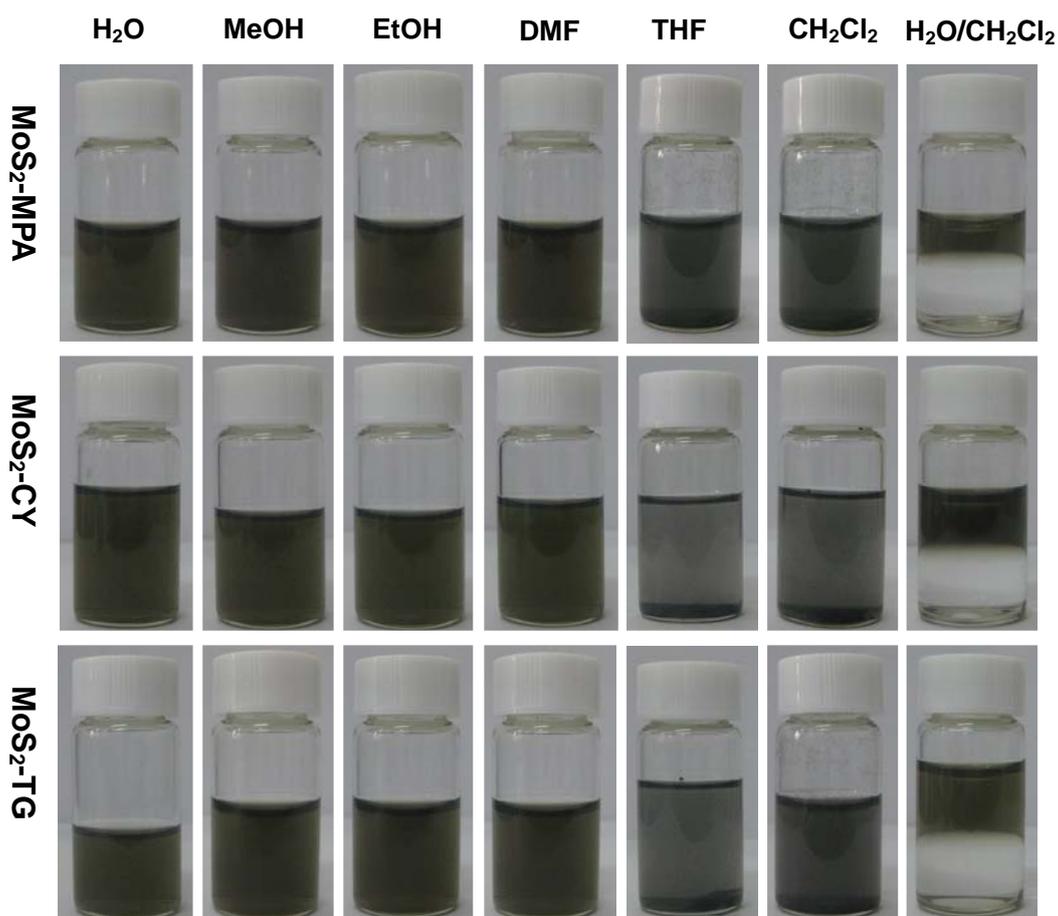


Fig. S1 Digital photographs of MoS₂-MPA, MoS₂-CY and MoS₂-TG in different solvents.

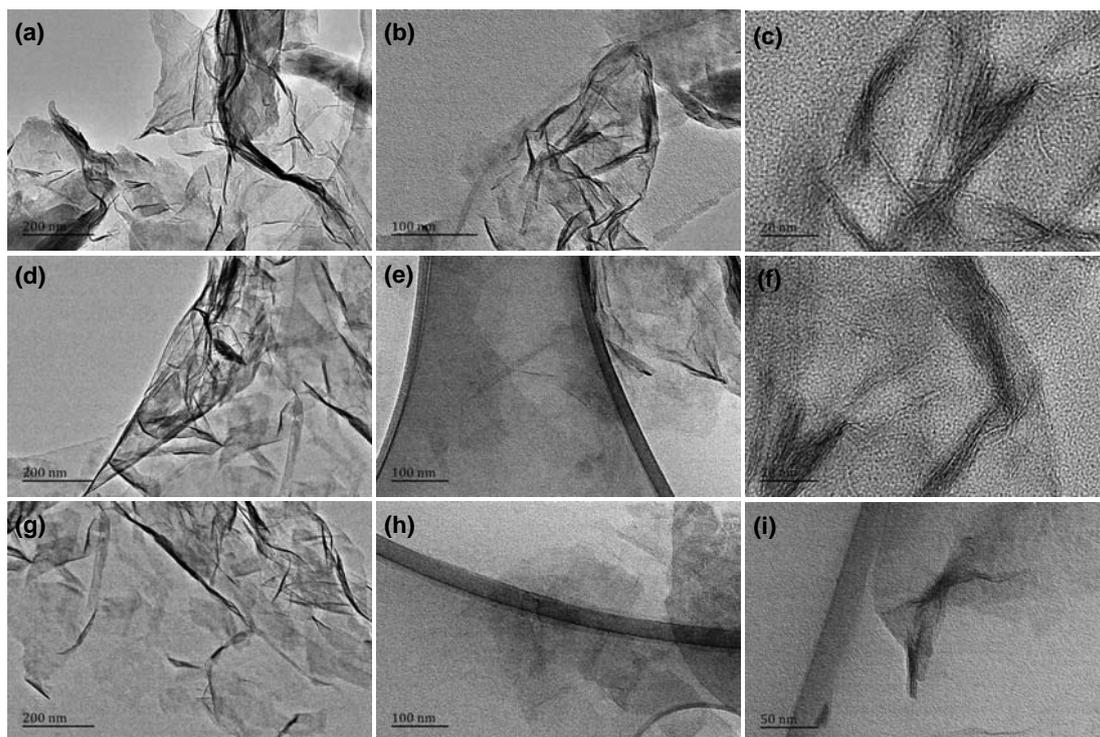


Fig. S2 Representative TEM images of MoS₂-MPA (a-c), MoS₂-CY (d-f) and MoS₂-TG (g-i).

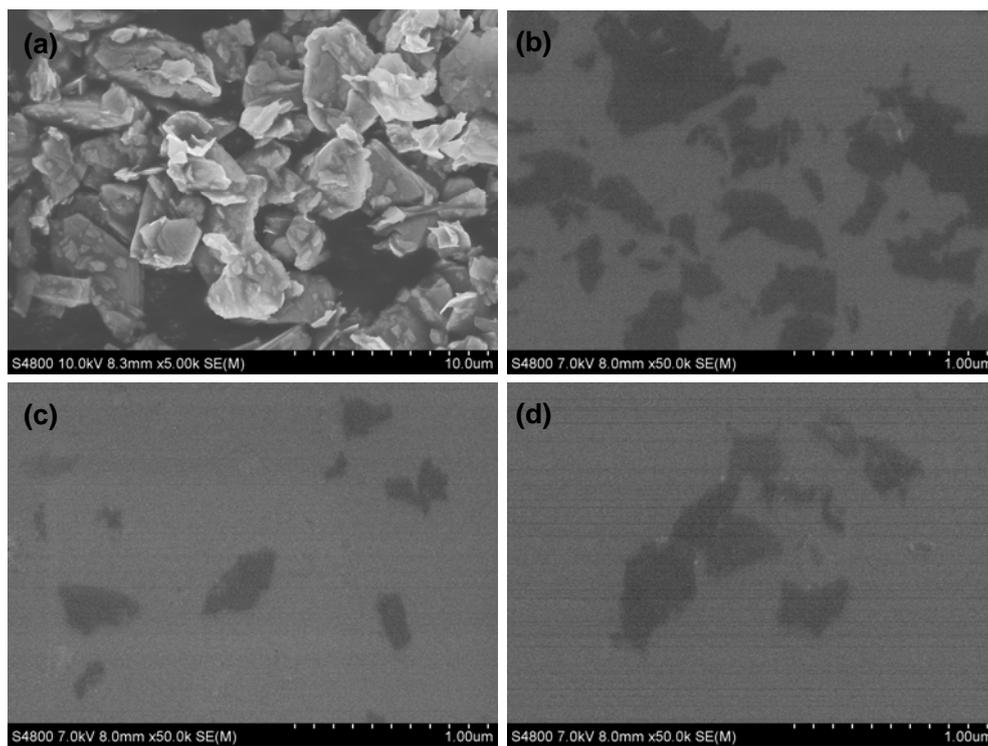


Fig. S3 Representative SEM images of bulk MoS₂ (a), MoS₂-MPA (b), MoS₂-CY (c) and MoS₂-TG (d). The (a) is secondary electrons image. The (b), (c) and (d) are backscattered electrons images on copper substrate.

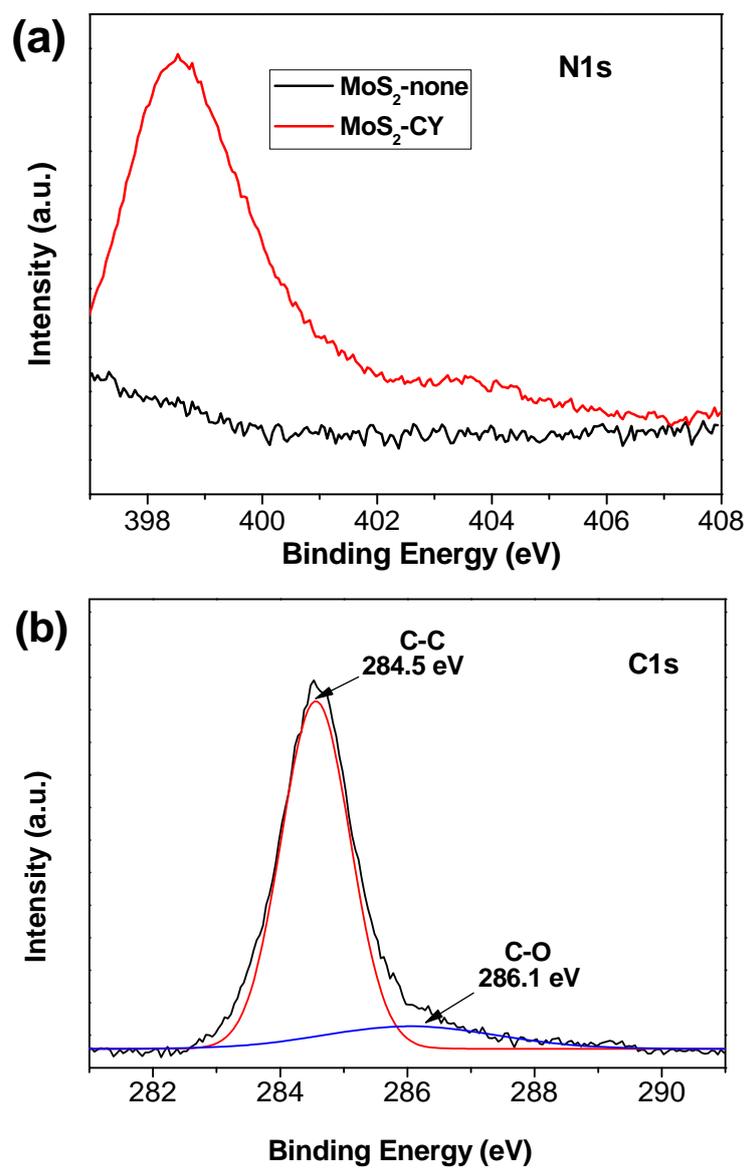


Fig. S4 (a) N1s spectra of MoS₂-none and MoS₂-CY. (b) C1s spectrum of MoS₂-TG.

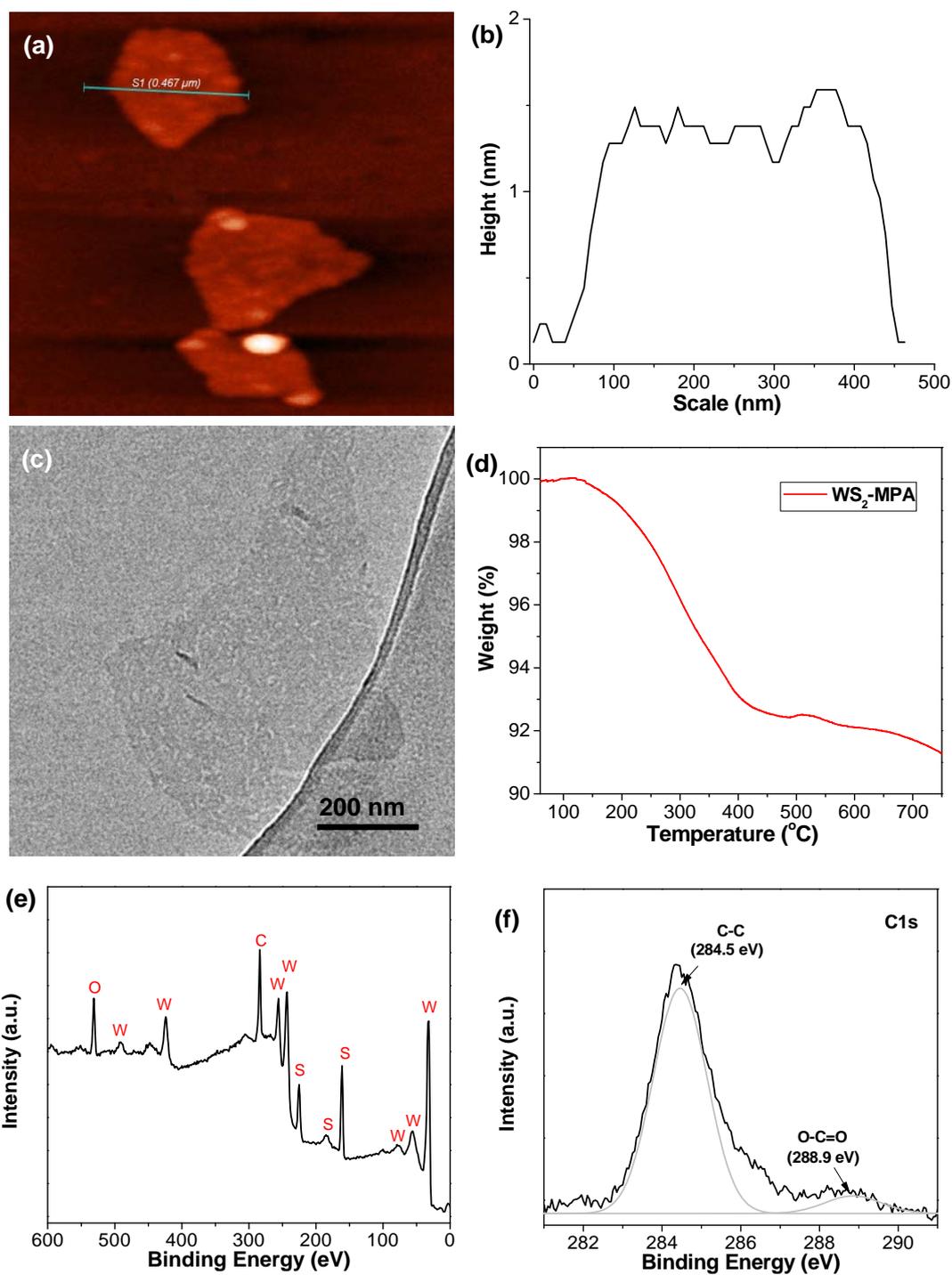


Fig. S5 (a) Representative AFM image of WS₂-MPA. The height profile in panel (b) is along the line in (a). (c) Representative TEM image of WS₂-MPA. (d) TGA curve of WS₂-MPA. XPS survey (e) and C1s (f) spectra of WS₂-MPA.

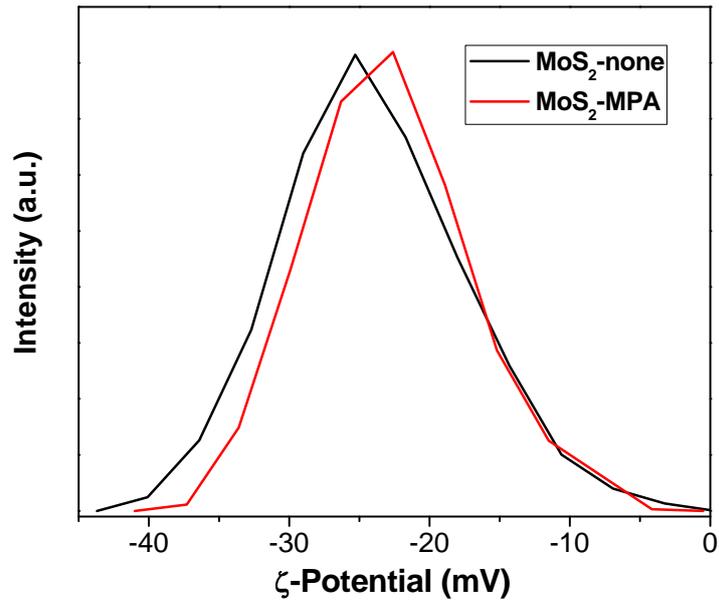


Fig. S6 ζ-potential of MoS₂-none and MoS₂-MPA.

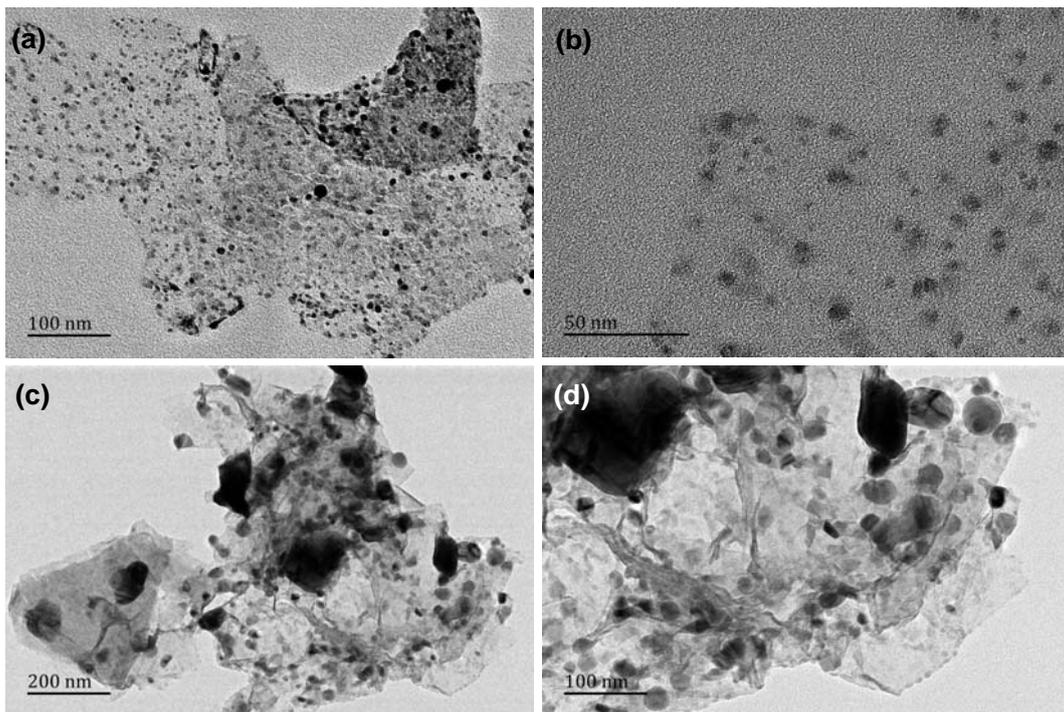


Fig. S7 Representative TEM images of MoS₂-Ag using MoS₂-MPA (a,b) and MoS₂-none (c,d) as substrate, respectively.

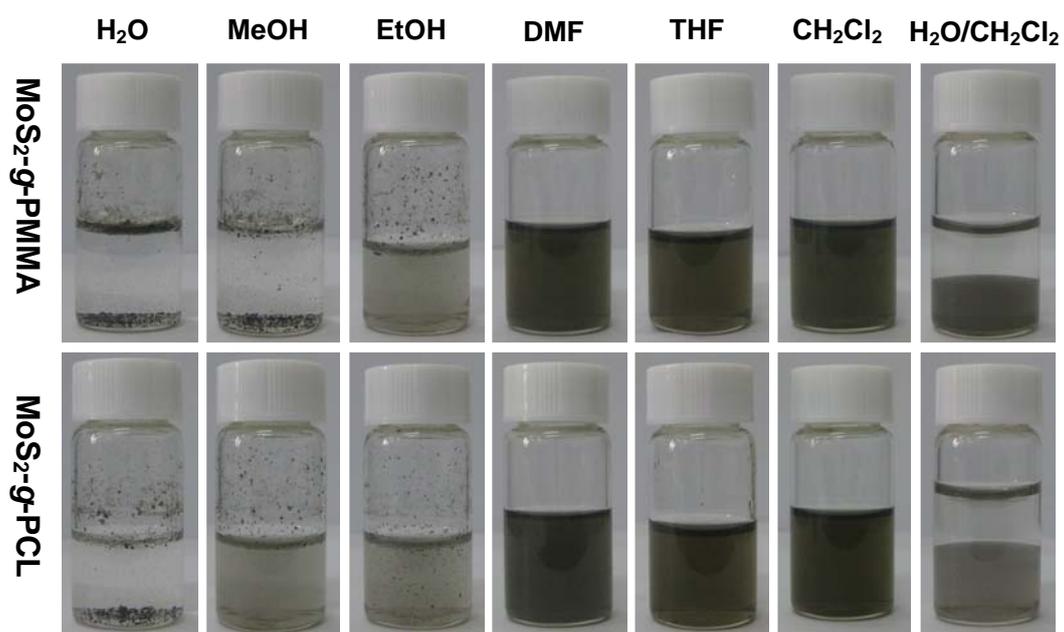


Fig. S8 Digital photographs of MoS₂-g-PMMA and MoS₂-g-PCL in different solvents.